SCLS145B - DECEMBER 1982 - REVISED MAY 1997

- **High-Current 3-State Outputs Drive Bus** Lines Directly or up to 15 LSTTL Loads
- **Bus-Structured Pinout**
- **Package Options Include Plastic** Small-Outline (DW) and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

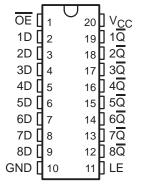
### description

These 8-bit transparent D-type latches feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

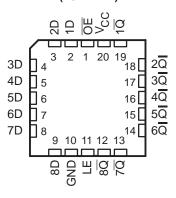
While the latch-enable (LE) input is high, the Q outputs follow the complements of the data (D) inputs. When LE is taken low, the outputs are latched at the inverses of the levels set up at the D inputs.

A buffered output-enable (OE) input places the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased high logic level provide the capability to drive bus lines without interface or pullup components.

SN54HC563 . . . J OR W PACKAGE SN74HC563...DW OR N PACKAGE (TOP VIEW)



SN54HC563 . . . FK PACKAGE (TOP VIEW)



OE does not affect internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The SN54HC563 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74HC563 is characterized for operation from -40°C to 85°C.

### **FUNCTION TABLE** (each latch)

	INPUTS	OU <u>T</u> PUT	
OE	LE	D	Q
L	Н	Н	L
L	Н	L	Н
L	L	Χ	$\overline{Q}_0$
Н	X	Χ	Z

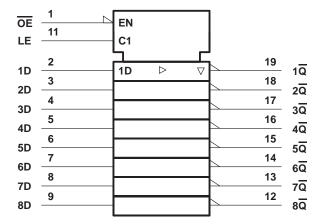


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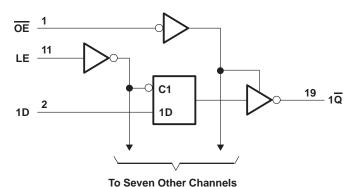
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### logic symbol<sup>†</sup>



<sup>&</sup>lt;sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

### logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range‡

Supply voltage range, V <sub>CC</sub>	–0.5 V to 7 V
Input clamp current, $I_{IK}$ ( $V_I < 0$ or $V_I > V_{CC}$ ) (see Note 1)	±20 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> ) (see Note 1)	±20 mA
Continuous output current, $I_O$ ( $V_O = 0$ to $V_{CC}$ )	±35 mA
Continuous current through V <sub>CC</sub> or GND	±70 mA
Package thermal impedance, $\theta_{JA}$ (see Note 2): DW package	97°C/W
N package	67°C/W
Storage temperature range, T <sub>sta</sub>	–65°C to 150°C

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
  - 2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.



## recommended operating conditions

			SI	SN54HC563			SN74HC563			
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT	
Vсс	Supply voltage		2	5	6	2	5	6	V	
		V <sub>CC</sub> = 2 V	1.5			1.5				
ViH	High-level input voltage	V <sub>CC</sub> = 4.5 V	3.15			3.15			V	
		VCC = 6 V	4.2			4.2				
	Low-level input voltage	V <sub>CC</sub> = 2 V	0		0.5	0		0.5		
VIL		V <sub>CC</sub> = 4.5 V	0		1.35	0		1.35	V	
		VCC = 6 V	0		1.8	0		1.8		
٧ı	Input voltage		0		VCC	0		VCC	V	
۷o	Output voltage		0		VCC	0		VCC	V	
		V <sub>CC</sub> = 2 V	0		1000	0		1000		
t <sub>t</sub>	Input transition (rise and fall) time	V <sub>CC</sub> = 4.5 V	0		500	0		500	ns	
		V <sub>CC</sub> = 6 V	0		400	0		400		
TA	Operating free-air temperature		-55		125	-40		85	°C	

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS		V	T <sub>A</sub> = 25°C			SN54HC563		SN74HC563		LINUT
PARAMETER			VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V	1.9	1.998		1.9		1.9		
		I <sub>OH</sub> = -20 μA	4.5 V	4.4	4.499		4.4		4.4		
Voн	VI = VIH or VIL		6 V	5.9	5.999		5.9		5.9		V
		$I_{OH} = -6 \text{ mA}$	4.5 V	3.98	4.3		3.7		3.84		
		$I_{OH} = -7.8 \text{ mA}$	6 V	5.48	5.8		5.2		5.34		
	VI = VIH or VIL	Ι <sub>ΟL</sub> = 20 μΑ	2 V		0.002	0.1		0.1		0.1	
			4.5 V		0.001	0.1		0.1		0.1	
VOL			6 V		0.001	0.1		0.1		0.1	V
		$I_{OL} = 6 \text{ mA}$	4.5 V		0.17	0.26		0.4		0.33	
		$I_{OL} = 7.8 \text{ mA}$	6 V		0.15	0.26		0.4		0.33	
lį	$V_I = V_{CC}$ or 0		6 V		±0.1	±100		±1000		±1000	nA
loz	$V_O = V_{CC}$ or 0		6 V		±0.01	±0.5		±10		±5	μΑ
Icc	$V_I = V_{CC}$ or 0,	I <sub>O</sub> = 0	6 V			8		160		80	μΑ
C <sub>i</sub>			2 V to 6 V		3	10		10		10	pF

## SN54HC563, SN74HC563 OCTAL TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS

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# timing requirements over recommended operating free-air temperature range (unless otherwise noted)

		V	T <sub>A</sub> = 2	25°C	SN54H	IC563	SN74H	C563	UNIT
		VCC	MIN	MAX	MIN	MAX	MIN	MAX	ONIT
		2 V	80		120		100		
t <sub>W</sub>	t <sub>W</sub> Pulse duration, LE high	4.5 V	16		24		20		ns
		6 V	14		20		17		
		2 V	50		75		63		
t <sub>su</sub>	Setup time, data before LE↓	4.5 V	10		15		13		ns
		6 V	9		13		11		
	Hold time, data after LE↓	2 V	5		5		5		
th		4.5 V	5		5		5		ns
		6 V	5		5		5		

# switching characteristics over recommended operating free-air temperature range, $C_L$ = 50 pF (unless otherwise noted) (see Figure 1)

DADAMETED	FROM	то		T,	λ = 25°C	;	SN54H	C563	SN74H	IC563	LIAUT
PARAMETER	(INPUT)	(OUTPUT)	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V		77	175		265		220	
	D	Q	4.5 V		26	35		53		44	
			6 V		23	30		45		37	ns
<sup>t</sup> pd			2 V		90	175		265		220	115
	LE	Any Q	4.5 V		27	35		53		44	
			6 V		23	30		45		37	
		Any Q	2 V		70	150		225		190	
t <sub>en</sub>	ŌĒ		4.5 V		24	30		45		38	ns
			6 V		21	26		38		32	
			2 V		47	150		225		190	
<sup>t</sup> dis	ŌĒ	Any Q	4.5 V		23	30		45		38	ns
			6 V		21	26		38		32	
			2 V		28	60		90		75	
t <sub>t</sub>		Any Q	4.5 V		8	12		18		15	ns
-			6 V		6	10		15		13	

## SN54HC563, SN74HC563 OCTAL TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS

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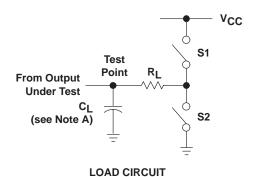
# switching characteristics over recommended operating free-air temperature range, $C_L$ = 150 pF (unless otherwise noted) (see Figure 1)

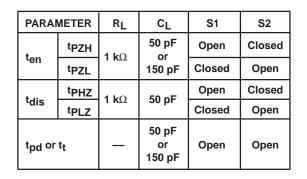
PARAMETER	FR FROM TO Vo.		V	Τ <sub>Δ</sub>	\ = 25°C	;	SN54H	IC563	SN74H	C563	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII	
			2 V		95	200		300		250		
	D	Q	4.5 V		33	40		60		50		
			6 V		29	34		51		43	20	
<sup>t</sup> pd	LE	Any Q	2 V		103	225		335		285	ns	
			4.5 V		33	45		67		57		
			6 V		29	38		57		48		
	ŌĒ	Any Q	2 V		85	200		300		250		
t <sub>en</sub>			Any Q	4.5 V		29	40		60		50	ns
			6 V		26	34		51		43		
			2 V		60	210		315		265		
t <sub>t</sub>		Any Q	4.5 V		17	42		63		53	ns	
			6 V		14	36		53		45		

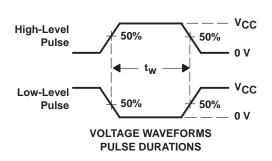
## operating characteristics, $T_A = 25^{\circ}C$

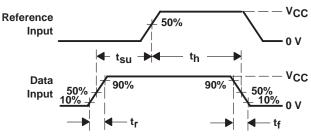
	PARAMETER	TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance per latch	No load	50	pF

### PARAMETER MEASUREMENT INFORMATION

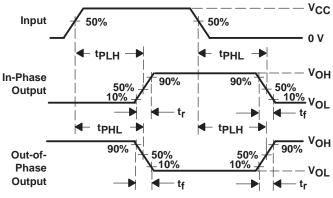


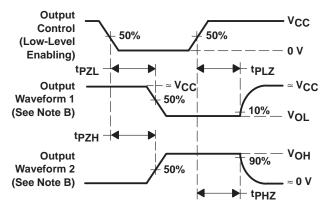






VOLTAGE WAVEFORMS
SETUP AND HOLD AND INPUT RISE AND FALL TIMES





VOLTAGE WAVEFORMS
PROPAGATION DELAY AND OUTPUT TRANSITION TIMES

VOLTAGE WAVEFORMS ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

NOTES: A. C<sub>L</sub> includes probe and test-fixture capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub> = 6 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. tpLZ and tpHZ are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



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